NSN 5961-00-754-5468

Transistor - Page 1 of 1

Demilitarization:

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-754-5468 **Inclosure Material:** Metal **Overall Length:** 0.859 inches **Overall Diameter:** 0.870 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc and 60.0 collector to emitter voltage, dc and 10.0 emitter to base voltage, dc **Power Rating Per Characteristic:** 85.0 watts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 wire hook **Specification Data:** 81349-mil-s-19500/173 government specification Shelf Life: N/a **Unit Of Measure:**